

IR Receiver Modules for Remote Control Systems



16672

MECHANICAL DATA

Pinning:

1 = OUT, 2 = GND, 3 = V_S

FEATURES

- Very low supply current
- Photo detector and preamplifier in one package
- Internal filter for PCM frequency
- Improved shielding against EMI
- Supply voltage: 2.5 V to 5.5 V
- Improved immunity against ambient light
- Insensitive to supply voltage ripple and noise
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



DESCRIPTION

The TSOP341.., TSOP343.. series are miniaturized receivers for infrared remote control systems. A PIN diode and a preamplifier are assembled on a lead frame, the epoxy package acts as an IR filter.

The demodulated output signal can be directly decoded by a microprocessor. The TSOP341.. is compatible with all common IR remote control data formats. The TSOP343.. is optimized to better suppress spurious pulses from energy saving fluorescent lamps but will also suppress some data signals.

This component has not been qualified according to automotive specifications.

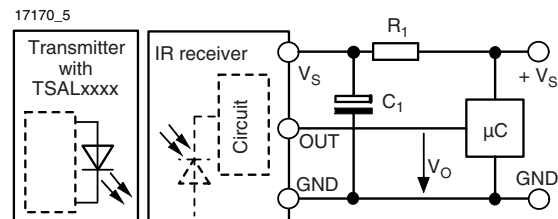
PARTS TABLE

CARRIER FREQUENCY	SHORT BURSTS AND HIGH DATA RATES (AGC1)	NOISY ENVIRONMENTS AND SHORT BURSTS (AGC3)
30 kHz	TSOP34130	TSOP34330
33 kHz	TSOP34133	TSOP34333
36 kHz	TSOP34136	TSOP34336
38 kHz	TSOP34138	TSOP34338
40 kHz	TSOP34140	TSOP34340
56 kHz	TSOP34156	TSOP34356

BLOCK DIAGRAM



APPLICATION CIRCUIT



R_1 and C_1 are recommended for protection against EOS. Components should be in the range of $33 \Omega < R_1 < 1 \text{ k}\Omega$, $C_1 > 0.1 \mu\text{F}$.

ABSOLUTE MAXIMUM RATINGS (1)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Supply voltage (pin 3)		V_S	- 0.3 to + 6.0	V
Supply current (pin 3)		I_S	3	mA
Output voltage (pin 1)		V_O	- 0.3 to ($V_S + 0.3$)	V
Output current (pin 1)		I_O	5	mA
Junction temperature		T_j	100	°C
Storage temperature range		T_{stg}	- 25 to + 85	°C
Operating temperature range		T_{amb}	- 25 to + 85	°C
Power consumption	$T_{amb} \leq 85 \text{ °C}$	P_{tot}	10	mW
Soldering temperature	$t \leq 10 \text{ s}$, 1 mm from case	T_{sd}	260	°C

Note

(1) Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect the device reliability.

ELECTRICAL AND OPTICAL CHARACTERISTICS (1)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply current (pin 3)	$E_v = 0$, $V_S = 3.3 \text{ V}$	I_{SD}	0.27	0.35	0.45	mA
	$E_v = 40 \text{ klx}$, sunlight	I_{SH}		0.45		mA
Supply voltage		V_S	2.5		5.5	V
Transmission distance	$E_v = 0$, test signal see fig. 1, IR diode TSAL6200, $I_F = 250 \text{ mA}$	d		45		m
Output voltage low (pin 1)	$I_{OSL} = 0.5 \text{ mA}$, $E_e = 0.7 \text{ mW/m}^2$, test signal see fig. 1	V_{OSL}			100	mV
Minimum irradiance	Pulse width tolerance: $t_{pi} - 5/f_0 < t_{po} < t_{pi} + 6/f_0$, test signal see fig. 1	$E_e \text{ min.}$		0.1	0.25	mW/m^2
Maximum irradiance	$t_{pi} - 5/f_0 < t_{po} < t_{pi} + 6/f_0$, test signal see fig. 1	$E_e \text{ max.}$	30			W/m^2
Directivity	Angle of half transmission distance	$\phi_{1/2}$		± 45		deg

Note

(1) $T_{amb} = 25 \text{ °C}$, unless otherwise specified

TYPICAL CHARACTERISTICS

$T_{amb} = 25 \text{ °C}$, unless otherwise specified



Fig. 1 - Output Active Low



Fig. 2 - Pulse Length and Sensitivity in Dark Ambient



Fig. 3 - Output Function



Fig. 6 - Sensitivity in Bright Ambient



Fig. 4 - Output Pulse Diagram



Fig. 7 - Sensitivity vs. Supply Voltage Disturbances



Fig. 5 - Frequency Dependence of Responsivity



Fig. 8 - Sensitivity vs. Electric Field Disturbances



Fig. 9 - Maximum Envelope Duty Cycle vs. Burst Length



Fig. 12 - Horizontal Directivity



Fig. 10 - Sensitivity vs. Ambient Temperature



Fig. 13 - Sensitivity vs. Supply Voltage



Fig. 11 - Relative Spectral Sensitivity vs. Wavelength

SUITABLE DATA FORMAT

The TSOP341.., TSOP343.. series are designed to suppress spurious output pulses due to noise or disturbance signals. Data and disturbance signals can be distinguished by the devices according to carrier frequency, burst length and envelope duty cycle. The data signal should be close to the band-pass center frequency (e.g. 38 kHz) and fulfill the conditions in the table below.

When a data signal is applied to the TSOP341.., TSOP343.. in the presence of a disturbance signal, the sensitivity of the receiver is reduced to insure that no spurious pulses are present at the output. Some examples of disturbance signals which are suppressed are:

- DC light (e.g. from tungsten bulb or sunlight)
- Continuous signals at any frequency
- Modulated noise from fluorescent lamps with electronic ballasts (see figure 14 or figure 15)



Fig. 14 - IR Signal from Fluorescent Lamp with Low Modulation



Fig. 15 - IR Signal from Fluorescent Lamp with High Modulation

	TSOP341..	TSOP343..
Minimum burst length	6 cycles/burst	6 cycles/burst
After each burst of length a minimum gap time is required of	6 to 70 cycles ≥ 10 cycles	6 to 35 cycles ≥ 10 cycles
For bursts greater than a minimum gap time in the data stream is needed of	70 cycles > 1.2 x burst length	35 cycles > 6 x burst length
Maximum number of continuous short bursts/second	2000	2000
Compatible to NEC code	yes	yes
Compatible to RC5/RC6 code	yes	yes
Compatible to Sony code	yes	no
Compatible to RCMM code	yes	yes
Compatible to r-step code	yes	yes
Compatible to XMP code	yes	yes
Suppression of interference from fluorescent lamps	Common disturbance signals are suppressed (example: signal pattern of fig. 14)	Even critical disturbance signals are suppressed (examples: signal pattern of fig. 14 and fig. 15)

Note

For data formats with long bursts (more than 10 carrier cycles) please see the data sheet for TSOP348.., TSOP344.

TSOP341.., TSOP343..

Vishay Semiconductors

IR Receiver Modules for
Remote Control Systems



PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.550-5169.11-4

Issue: 10; 08.06.04

16003



OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9